

Original Article

Effects of Partial Substitution of Bromine on the Structural, Electronic, and Optical Properties of CsPbI₃ Insight from First Principles Calculations

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Abstract - Adjusting the composition by partial substitution of halide gives a sure way of improving phase stability and fine-tuning the optoelectronic properties of fully inorganic perovskite halides. In this study, first-principles Density Functional Theory (DFT) computations with Spin–Orbit Coupling (SOC) were used to examine the impact of partial bromine integration on the optical, electronic, and structural properties of CsPbI₃. The enhanced CsPbI₂Br structure shows a slight lattice contraction from 6.29 to 6.21 Å, compatible with the smaller ionic radius of bromine, which raises the Goldschmidt tolerance factor from 0.89 to 0.91 and thus stabilizes the cubic phase. The material therefore maintains a direct band gap of 1.68 eV at the R point, positioning it within the maximum range for single-junction solar cells. Projected density-of-states analysis shows that the valence band largely originates from I-5p and Br-4p orbitals hybridized with Pb-6s states, while the conduction band is influenced by Pb-6p orbitals, resulting in strong orbital coupling and low carrier effective masses. Optical analyses show a high static dielectric constant ($\epsilon_r(0) = 5.8$), very high visible-light absorption ($>10^5 \text{ cm}^{-1}$) and low reflectivity (<0.25), showing exceptional light-harvesting potential. An energy-loss peak at 5.1 eV corresponds to bulk plasmon excitation, and the optical conductivity is highest at 3.1 eV, indicating strong inter-band transitions. On the whole, the incorporation of bromine improves the electronic quality, optical response, and structural robustness of CsPbI₃, ranking CsPbI₂Br as a bright and stable material for future generations of perovskite-based photovoltaic and optoelectronic applications.

Keywords - Density functional theory, Lattice contraction, Optoelectronic properties, Phase stability, Structural robustness.

1. Introduction

Halide perovskites are one of the grey areas where intense research in material sciences is going on in recent times due to their low-cost production, compositional adjustability, and remarkable optoelectronic properties. Their ability to combine robustness, strong light absorption, and high charge-carrier mobility makes them usable for light-emitting applications, thermoelectric, and photovoltaic. [1,2] Among others, non-organic cesium lead halide perovskites (CsPbX₃, X = I, Br, Cl) have drawn special attention for their enhanced thermal and phase stability compared to Hybrid Organic–Inorganic Perovskites (HOIPs). [3] Their bandgap can be finely honed across the visible spectrum, allowing excellent control of optical and electronic properties necessary for upcoming optoelectronic devices. [4,5]

One of the most efficient ways to mastermind the performance of these materials is by the halide substitution method, which directly affects the optical absorption, electronic band dispersion, and lattice constant. Substituting iodide with bromine or chlorine allows continuous control of

band gaps and stability. [6,7] Applying Density Functional Theory (DFT), Yu [6] reported that increasing bromine concentration in CsPbI_{3-x}Br_x creates lattice contraction and hence the widening of bandgap from about 1.36 eV (CsPbI₃) to 2.23 eV (CsPbBr₃), which is in line with experimental results. Likewise, Wang and Han [8,9] found that bromine integration improves the phase stability of cubic CsPbI₃ and aids its thermoelectric performance, with room-temperature ZT values approaching 0.99. These findings emphasize bromine's twofold function in stabilizing perovskite structures and assisting their optoelectronic response.

Computational study using different exchange–correlation functionals such as mBJ, HSE06, and GGA-PBE has effectively reproduced experimental trends in these materials. [10,11] Many recent studies have centered on extreme compositions; either iodide-rich (CsPbI₃) or bromide-rich (CsPbBr₃), or ascertained the complete range of substitution in CsPbI_{3-x}Br_x robust solutions. [12,13] However, the midway composition CsPbI₂Br, which represents partial bromine substitution, has attracted limited attention. This



compound is important because it incorporates the morphological stability of bromine-rich phases with the acceptable thin bandgap of iodine-rich ones, making it an excellent prospect for high-efficiency solar absorbers and photonic devices.

A major issue in the existing research is that studies often use different methods, making it hard to compare results. Results in the literature most times vary with the use of different exchange–correlation functionals, supercell models, and treatment of Spin–Orbit Coupling (SOC), which plays an important part in defining the bandgap of lead halide perovskites. [14,15] This discrepancy makes it difficult to have a clear understanding of how partial bromine substitution affects the structural and hence optoelectronic interplay in CsPbI₂Br.

Therefore, this research tackles this discrepancy in knowledge by using, as a matter of fact, first-principles DFT computations to study the effects of partial bromine substitution on the structural, electronic, and optical properties of CsPbI₃. By sustaining steady computational requirements, including SOC treatment and convergence accuracy, this study aims to ascertain a clear interdependence between bromine merger, optical response, electronic band structure, and lattice behavior. The results are therefore expected to give a distinct insight into mixed-halide compound thin film and a guiding principle for the design of CsPbI₂Br-based materials for effective and stable optoelectronic applications. In this research, the exchange–correlation interactions were handled by employing the Generalized Gradient Approximation (GGA) within the Perdew–Burke–Ernzerhof (PBE) functional and the hybrid functional (HSE06) for better precision. The plane-wave basis set approach was used together with Projector Augmented-Wave (PAW) and norm-conserving pseudopotentials to explain the electron–ion interactions thoroughly. [16,17]

2. Materials and Methods

2.1. Materials

The following are the materials used in this work:

- Dell Laptop Latitude E6530
- Quantum espresso code version 7.4.1
- High Performance Computer (HPC)
- Internet router
- Source of electricity

2.2. Methods

2.2.1. Theoretical Framework

The Kohn-Sham equation in DFT is given by

$$\left[-\frac{\hbar^2}{2m} \nabla^2 + V_{\text{ext}}(r) + V_H(r) + V_{\text{xc}}(r) \right] \psi_i(r) = \epsilon_i \psi_i(r) \quad (1)$$

Where $V_{\text{ext}}(r)$ = external potential from nuclei, $V_H(r)$ = Hartree potential and $V_{\text{xc}}(r)$ = exchange–correlation potential.

2.2.2. Optical Properties

They include dielectric function, refractive index, extinction coefficient, absorption coefficient, reflectivity, energy loss function, and optical conductivity. The dielectric function describes a material's response to an electromagnetic wave. The real part $\epsilon_1(\omega)$ corresponds to dispersion, while the imaginary part $\epsilon_2(\omega)$ relates to absorption. For PV materials, a high ϵ_2 in the visible region, it enhances light absorption, while a suitable ϵ_1 promotes effective screening and charge separation. [18]

The linear optical properties are obtained from the frequency-dependent complex dielectric function given by:

$$\epsilon(\omega) = \epsilon_1(\omega) + i\epsilon_2(\omega) \quad (2)$$

Where ω is the photon frequency. The real part through the Kramers-Kronig relation [19] is given by

$$\epsilon_1(\omega) = 1 + \frac{2}{\pi} P \int_0^\infty \frac{\omega' \epsilon_2(\omega')}{\omega'^2 - \omega^2} d\omega' \quad (3)$$

$$\epsilon_2(\omega) = \frac{8\pi^2 e^2}{\Omega} \sum_{k,v,c} |\psi_k^c| |u \cdot r| |\psi_k^v|^2 \delta(E_k^c - E_k^v - \hbar\omega) \quad (4)$$

The other optical properties were obtained using Equations 1, 2, 3, and 4.

2.2.3. Computational Details

First-principles calculations based on Density Functional Theory (DFT) were done using the Quantum ESPRESSO simulation package [20,21] to investigate the structural, electronic, and optical properties of the hybrid halide perovskite CsPbI₂Br. The Perdew–Burke–Ernzerhof

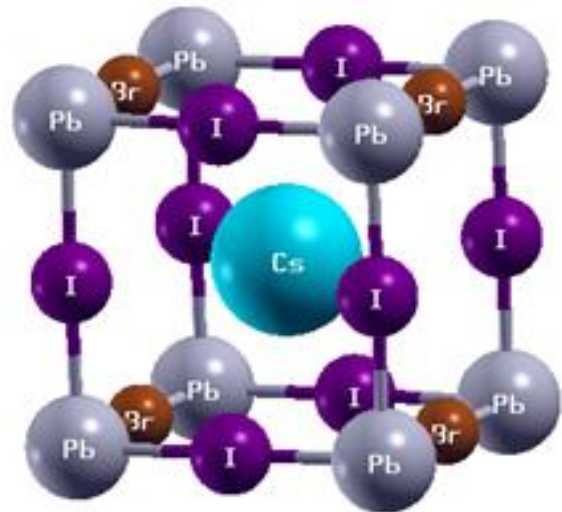


Fig. 1 Crystal Structure for CsPbI₂Br

(PBE) discretization of the Generalized Gradient Approximation (GGA), [17] was used to describe the exchange–correlation functional. To accurately capture relativistic effects important for systems containing heavy elements, such as Pb and I, Spin-Orbit Coupling (SOC) was specifically included in all electronic structure calculations.

Norm-conserving pseudopotentials were incorporated for Cs, Pb, I, and Br atoms; and the Kohn–Sham orbitals were expanded in a plane-wave basis set with a kinetic energy cutoff of 80 Ry, which secured the convergence of total energy and structural parameters. Brillouin zone integrations were carried out using a Monkhorst–Pack k-point mesh of $8 \times 8 \times 8$ for Self-Consistent Field (SCF) and $16 \times 16 \times 16$ for the Non-Self-Consistent Field (NSCF) calculations.[22] The based perovskite crystal structure was fully optimized using the variable-cell relaxation (vc-relax) method until the total energy change was less than 1×10^{-6} Ry and the Hellmann–Feynman forces on each atom were below 1×10^{-4} Ry/Bohr. Both lattice parameters and atomic positions were allowed to relax without symmetry restraints.[21,23]

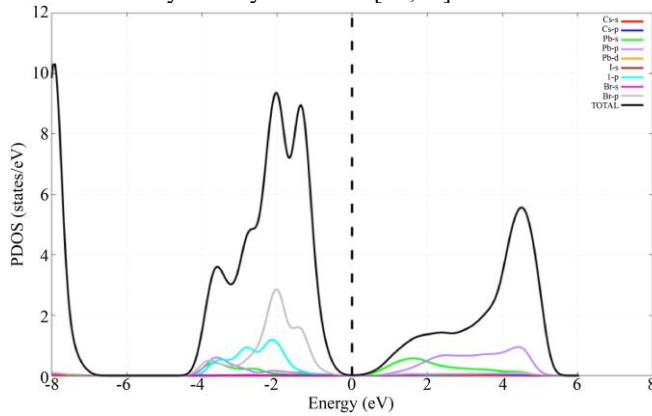


Fig. 2 Projected Density of States for CsPbI₂Br

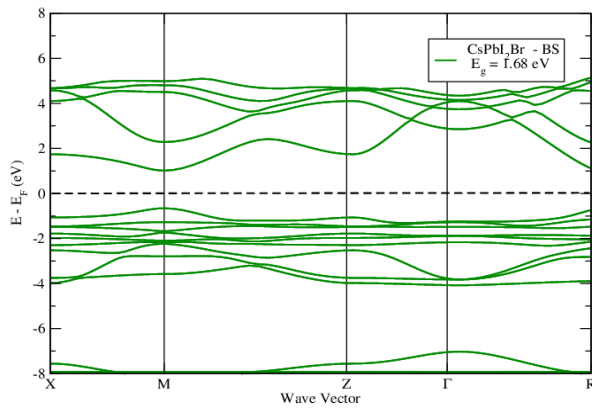


Fig. 3 Band Structure for CsPbI₂Br

The electronic band structure was calculated along high-symmetry paths in the Brillouin zone using the optimized lattice geometry, with SOC included self-consistently. The optical properties were calculated within the Independent Particle Approximation (IPA) using the inter-band transition

matrix elements deduced from the DFT wave functions. The frequency-dependent complex dielectric function, $\epsilon(\omega) = \epsilon_1(\omega) + i\epsilon_2(\omega)$, was obtained; from which derived optical constants such as refractive index, extinction coefficient, absorption coefficient, energy loss function, reflectivity, and optical conductivity were assessed. [24]

This computational order provides a balanced treatment of accuracy and computational efficiency, ensuring reliable prediction of structural, electronic, and optical properties for CsPbI₂Br.

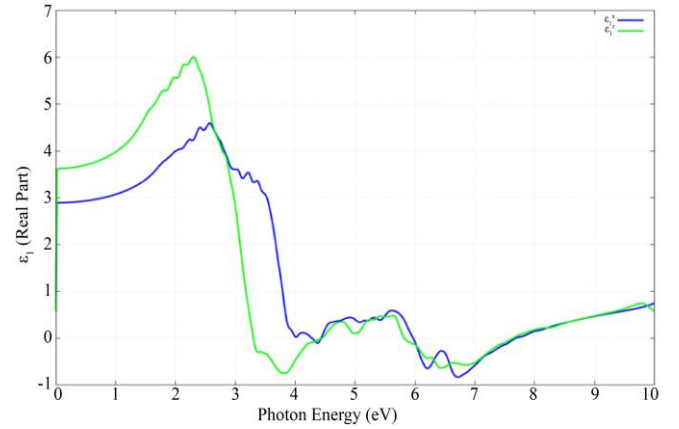


Fig. 4 Real dielectric for CsPbI₂Br

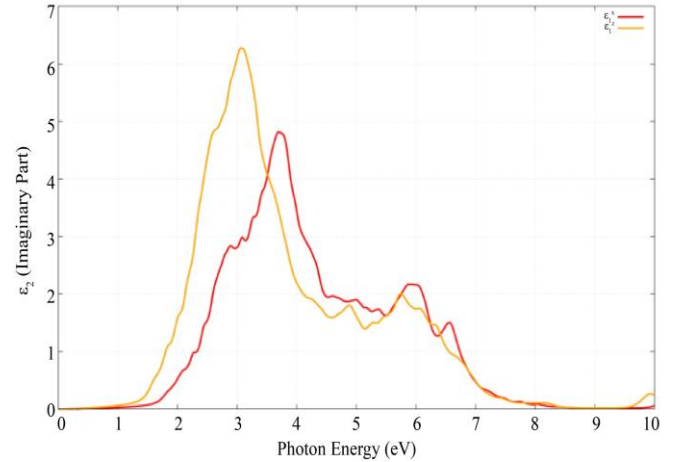


Fig. 5 Imaginary dielectric for CsPbI₂Br

3. Results and Discussion

3.1. Structural Properties of CsPbI₂Br

Figure 1 shows the optimized cubic perovskite crystal structure ($pm\bar{3}m$) of CsPbI₂Br, as calculated from DFT geometry optimization. In this arrangement, Pb²⁺ cations are positioned centrally within corner-sharing [PbX₆]⁴⁻ octahedra, where X stands for the halide ions (two iodides and one bromide). Cesium cations occupy the rectified octahedron A-site voids, balancing the configuration through electrostatic interactions. [25]

3.1.1. Lattice Parameters

Upon replacing one of the iodide ions in CsPbI₃ with a smaller bromide ion, the improved lattice constant decreases from about 6.29 Å (pristine CsPbI₃) to 6.21 Å for CsPbI₂Br. This 1.3% contraction is consistent with the ionic radius difference between Br⁻ (1.96 Å) and I⁻ (2.20 Å). [26] This contraction increases the Goldschmidt tolerance factor (*t*), which is given by the formula:

$$t = \frac{r_A + r_X}{\sqrt{2}(r_B + r_X)} \quad (5)$$

Where *r_A*, *r_B*, and *r_X* represent the ionic radii of Cs⁺, Pb²⁺, and the halide, respectively. For CsPbI₂Br, *t* = 0.91, as

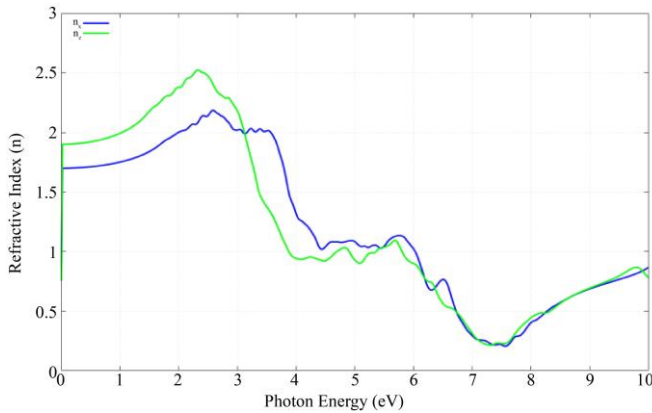


Fig. 6 Refractive Index for CsPbI₂Br

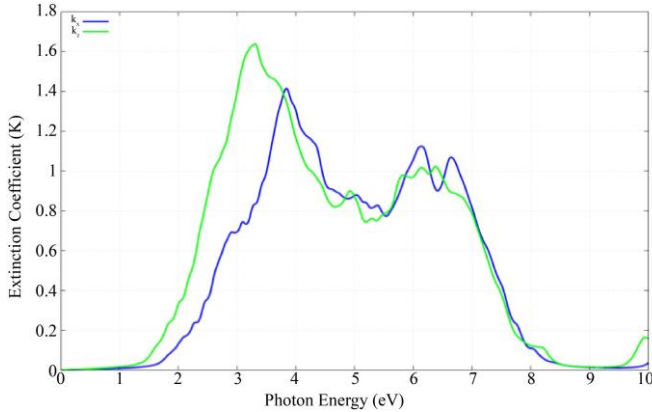


Fig. 7 The Extinction Coefficient

3.1.2. Bond Lengths and Octahedral Distortion

The Pb–I bonds in CsPbI₂Br moderate 3.19 Å, whereas Pb–Br bonds reduce to about 2.95 Å, showing the smaller size and larger electronegativity of Br. This unsymmetric bonding barely varies the electronic neighborhood of the Pb²⁺ cations without noticeably deforming the octahedral coupling. The [PbX₆] units stay almost perfect with bond angles close to 180°, maintaining the isotropic charge transport routes that are important for efficient photovoltaic performance. [28]

3.2. Electronic Properties CsPbI₂Br

The CsPbI₂Br's electronic properties, as shown in Figures 2 and 3, present an explicit, semiconducting characteristic with a direct band gap found at the R point of the Brillouin zone. The computed band gap of 1.68 eV is comparable with values given in previous theoretical and experimental works on mixed halide perovskites, which often span 1.6 eV to 1.8 eV, hence asserting its relevance for single-junction photovoltaic usage, especially where maximum efficiency is taken to be near 1.5–1.7 eV. [29] The direct band gap shows that electron–hole pairs can be agitated without impurity, being an advantage for strong optical absorption in the visible spectrum.

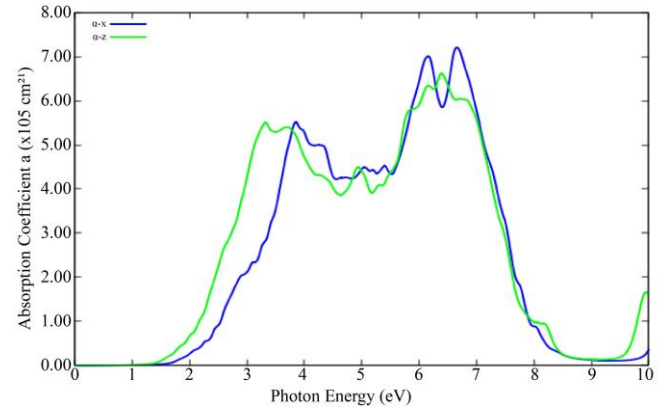


Fig. 8 Absorption Coefficient for CsPbI₂Br

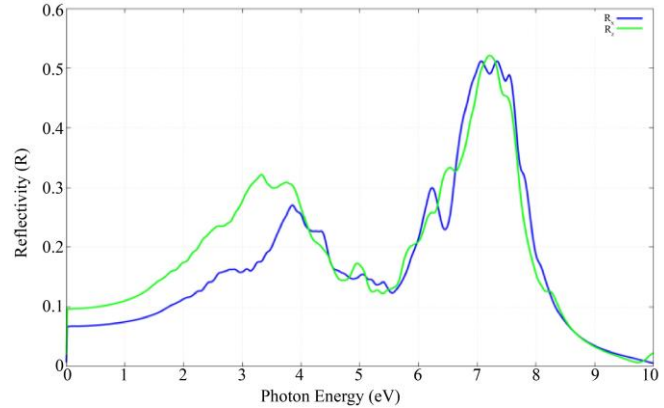


Fig. 9 Reflectivity for CsPbI₂Br

The Projected Density Of States (PDOS) in Figure 2 depicts that the Valence Band Maximum (VBM) is mainly formed by the halide p states; particularly, a strong hybridisation between I-5p and Br-4p orbitals with less contributions from Pb-6s states. However, the Conduction Band Minimum (CBM) is mostly made up of Pb-6p orbitals with a small mixture from halogen p states. This orbital framework is compatible with the electronic structure of lead halide perovskites, where the repulsive interplay between Pb-6p and halogen-p states orders the shape and magnitude of the band gap. [30, 31] The clear features in the PDOS close to the Fermi level also show a rather low density of trap states, which is commendable for effective carrier transport.

From the band structure in Figure 3, the dispersion of both conduction and valence bands close to the band edges is prominent, showing a small effective mass for charge carriers. This indicates high carrier mobility, which is important for decreasing recombination losses in photovoltaic devices. [32]

On the whole, the composite of a direct band gap in the maximum photovoltaic range, strong band dispersion, and clean PDOS features places CsPbI₂Br as an excellent light-absorbing material for solar cells. The mixed halide makes up (I and Br), which not only affects the band gap but also clearly promotes stability, contrasted to the pure iodide match, giving a balanced concession between efficiency and durability. [33]

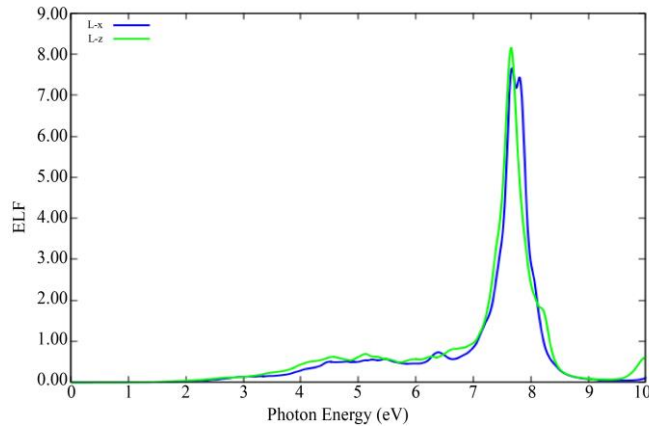


Fig. 10 Energy Loss Function for CsPbI₂Br

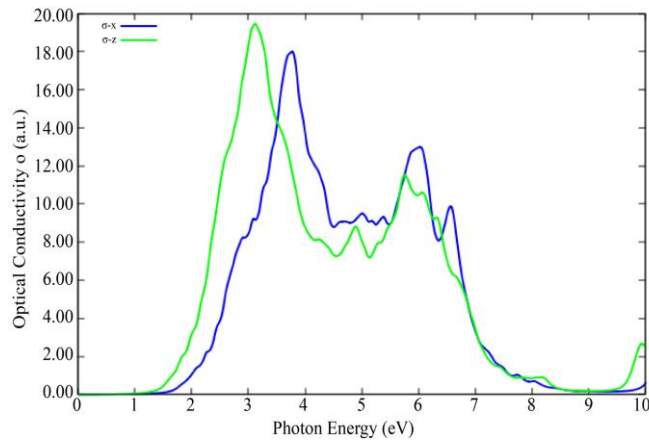


Fig. 11 Optical Conductivity for CsPbI₂Br

3.3. Optical Properties of CsPbI₂Br

The optical properties of CsPbI₂Br were obtained from first-principles computations using the dielectric function protocol, and the outcomes are given in Figures 4 - 11. These properties give insight into light-matter interactions of the compound, which are crucial for its photovoltaic and optoelectronic performance. [31, 32]

3.3.1. Dielectric Function

The real part of the dielectric constant (see Figure 4) attains a peak stationary value of about $\epsilon_1(0) = 5.8$, showing

strong electronic polarizability. This suggests effective safeguarding of Coulomb interactions, which is beneficial for exciton dissolution in solar cells. The curve shows a slow decrease with photon energy, with an outstanding apex in the visible region, showing strong inter-band transitions.

The imaginary part of the dielectric constant (see Figure 5) reveals remarkable absorption peaks about 2.1 eV and 4.8 eV, comparable to direct electronic transitions from the VBM (halogen p orbitals) to the CBM (Pb-6p orbitals). The beginning of $\epsilon_2(\omega)$ takes place near 1.9 eV, which matches well with the computed direct band gap. [32]

3.3.2. Refractive Index

The refractive index spectrum (see Figure 6) reveals a large constant value of $n(0) = 2.3$, showing strong light-bending ability, which can enhance photon confinement in thin-film devices.

The refractive index is maximum at 2.6 about 2.1 eV, coinciding with the primary $\epsilon_2(\omega)$ peak, before gradually decreasing in the UV range. [31]

3.3.3. Extinction Coefficient

The extinction coefficient (see Figure 7) increases abruptly at the absorption edge (1.9 eV), showing the onset of notable photon absorption. It reaches its peak close to 0.8 at 2.1 eV, thus supporting the strong optical transitions in the visible range. [32]

3.3.4. Absorption Coefficient

Figure 8 indicates that CsPbI₂Br shows a very high absorption coefficient surpassing 10^5 cm^{-1} across most of the visible spectrum, exceeding the threshold required for efficient solar harvesting. The absorption onset at 1.9 eV makes the material suitable for visible-light photovoltaics, while the prolonged absorption into the UV range proposes suitability for tandem or UV photo detector applications. [31]

3.3.5. Reflectivity

As shown in Figure 9, the reflectivity stays below 0.25 in the visible range, reducing light losses due to reflection. The curve is a bit maximum in the UV (0.32), in line with improved scattering at higher photon energies. [32]

3.3.6. Energy Loss Function

The energy loss function (see Figure 10) indicates a leading maximum at 5.1 eV, comparable to the bulk plasma frequency (ω_p).

This is a reflection of strong collective oscillations of free electrons at this energy, which is paramount for resolving the material's high-frequency optical characteristics. [32]

3.3.7. Optical Conductivity

Figure 11 shows that the optical conductivity increases abruptly from the peak of the band gap edge of about 3.1 eV,

comparable to the dominant inter-band transitions. This high conductivity in the visible range shows efficient photo carrier generation upon light absorption.[31]

Thus, optical analysis shows that CsPbI₂Br has a direct band gap (1.9 eV), low reflectivity, high refractive index, and remarkably high absorption in the visible region. It is seen that the optical properties of CsPbI₂Br are maximal on the z-axis than on the x-axis. These properties contribute to making the material a good candidate for UV-selective optoelectronic devices, top layers in tandem architectures, and single-junction solar cells. The layout between electronic structure and optical characteristics additionally underscores the relevance of CsPbI₂Br for high-efficiency, stable photovoltaic applications. [32, 33]

4. Conclusion

Partially substituting bromine in CsPbI₃ to obtain CsPbI₂Br considerably ameliorates the material's structural stability, producing a more sturdy cubic phase with a direct band gap of 1.68 eV, which is excellent for solar energy conversion. The resulting CsPbI₂Br compound shows excellent visible-light absorption, strong dielectric response, and low reflectivity, making it a promising and durable candidate for high-performance perovskite solar cells and advanced optoelectronic applications.

Acknowledgement

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